- State-of-the-Art Advanced BiCMOS Technology (ABT) Widebus™ Design for 2.5-V and 3.3-V Operation and Low Static **Power Dissipation**
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- High Drive (-24/24 mA at 2.5-V and -32/64 mA at 3.3-V V_{CC})
- **Power Off Disables Outputs, Permitting Live Insertion**
- **High-Impedance State During Power Up** and Power Down Prevents Driver Conflict
- Use Bus Hold on Data Inputs in Place of **External Pullup/Pulldown Resistors to** Prevent the Bus From Floating
- **Auto3-State Eliminates Bus Current** Loading When Output Exceeds V_{CC} + 0.5 V
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model; and Exceeds 1000 V **Using Charged-Device Model, Robotic** Method
- Flow-Through Architecture Facilitates **Printed Circuit Board Layout**
- Distributed V_{CC} and GND Pin Configuration **Minimizes High-Speed Switching Noise**
- **Package Options Include Plastic Shrink** Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package

SN54ALVTH16240 . . . WD PACKAGE SN74ALVTH16240 . . . DGG, DGV, OR DL PACKAGE (TOP VIEW)

		_		1
10E	1	\cup	48	20E
1Y1 [2		47] 1A1
1Y2 [3		46] 1A2
GND [4		45	GND
1Y3 [5		44] 1A3
1Y4 [6		43] 1A4
v _{cc} [7		42] v _{cc}
2Y1 [8		41] 2A1
2Y2 [9		40	2A2
GND [10		39	GND
2Y3 [11		38	2A3
2Y4 [12		37] 2A4
3Y1 [13		36	3A1
3Y2 [14		35	3A2
GND [15		34] GND
3Y3 [16		33] 3A3
3Y4 [17		32] 3A4
v _{cc} [18		31] v _{cc}
4Y1 [19		30] 4A1
4Y2 [20		29] 4A2
GND [28	GND
4Y3 [27	4A3
4 <u>Y4</u> [23		26	
4 <mark>0E</mark> [24		25] 3 <u>OE</u>

description

The 'ALVTH16240 devices are 16-bit buffers/line drivers designed for 2.5-V or 3.3-V V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

These devices are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus is a trademark of Texas Instruments Incorporated

SN54ALVTH16240, SN74ALVTH16240 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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description (continued)

The devices can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. The devices provide inverting outputs and symmetrical active-low output-enable (OE) inputs.

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

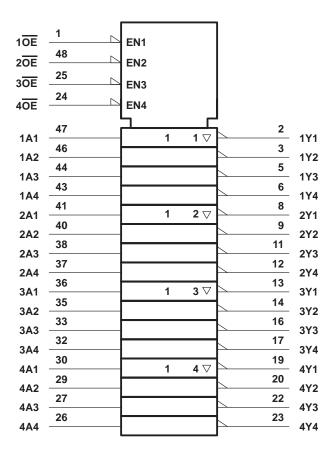
Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN54ALVTH16240 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ALVTH16240 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each 4-bit buffer)

INP	JTS	OUTPUT
OE	Α	Υ
L	Н	L
L	L	Н
н	Χ	Z

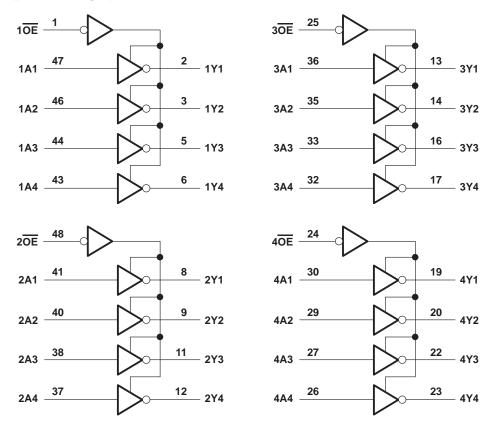
logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, V _O (see Note 1)	–0.5 V to 7 V
Output current in the low state, IO: SN54ALVTH16240	96 mA
SN74ALVTH16240	128 mA
Output current in the high state, IO: SN54ALVTH16240	–48 mA
SN74ALVTH16240	
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ _{JA} (see Note 2): DGG package	89°C/W
DGV package	93°C/W
DL package	94°C/W
Storage temperature range, T _{sto}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.



SN54ALVTH16240, SN74ALVTH16240 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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recommended operating conditions, V_{CC} = 2.5 V \pm 0.2 V (see Note 3)

			SN54	ALVTH1	6240	SN74	ALVTH1	6240	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage	2.3		2.7	2.3		2.7	V	
VIH	High-level input voltage	1.7		1/2	1.7			V	
V _{IL}	Low-level input voltage		Z	0.7			0.7	V	
VI	Input voltage	0	Vcc	5.5	0	VCC	5.5	V	
loн	High-level output current			1	-6			-8	mA
la.	Low-level output current			5	6			8	mA
lOL	Low-level output current; current duty cycle ≤ 5	50%; f ≥ 1 kHz	20	7	18			24	IIIA
Δt/Δν	Input transition rise or fall rate	Q		10			10	ns/V	
Δt/ΔV _{CC}	Power-up ramp rate	200			200			μs/V	
TA	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

recommended operating conditions, V_{CC} = 3.3 V \pm 0.3 V (see Note 3)

			SN54	ALVTH1	6240	SN74	UNIT		
			MIN	TYP	MAX	MIN	TYP	MAX	UNII
Vcc	Supply voltage	3		3.6	3		3.6	V	
VIH	High-level input voltage		2		h	2			V
V _{IL}	Low-level input voltage		3	0.8			0.8	V	
VI	Input voltage	0	VCC	5.5	0	Vcc	5.5	V	
IOH	High-level output current			1	-24			-32	mA
lou	Low-level output current			2	24			32	mA
lOL	Low-level output current; current duty cycle ≤	50%; f≥1 kHz		5	48			64	IIIA
Δt/Δν	Input transition rise or fall rate	Q		10			10	ns/V	
Δt/ΔV _{CC}	Power-up ramp rate	200			200			μs/V	
T _A	Operating free-air temperature	·	-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted)

	ND AMETED	TEST O	ONDITIONS	SN54	ALVTH1	6240	SN74	ALVTH1	6240	LINUT
PA	ARAMETER	TEST C	ONDITIONS	MIN	TYP [†]	MAX	MIN	TYP†	MAX	UNIT
٧ıK		$V_{CC} = 2.3 \text{ V},$	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	$I_{OH} = -100 \mu A$	V _{CC} -0.	V _{CC} -0.2		V _{CC} -0.2			
VOH		V _{CC} = 2.3 V	$I_{OH} = -6 \text{ mA}$	1.8						V
		vCC = 2.3 v	I _{OH} = -8 mA				1.8			
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I _{OL} = 100 μA			0.2			0.2	
			$I_{OL} = 6 \text{ mA}$			0.4				
VOL		V _{CC} = 2.3 V	$I_{OL} = 8 \text{ mA}$						0.4	V
		VCC = 2.3 V	I _{OL} = 18 mA			0.5				
			I _{OL} = 24 mA						0.5	
	Control inputs	$V_{CC} = 2.7 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	V _I = 5.5 V			<u>\$</u> 10			10	
II	I _I Data inputs		V _I = 5.5 V		Š	10			10	μΑ
		V _{CC} = 2.7 V	VI = VCC		1 -5				1	
			V _I = 0							
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V		25				±100	μΑ
I _{BHL} ‡		$V_{CC} = 2.3 \text{ V},$	V _I = 0.7 V		115			115		μΑ
IBHH§		$V_{CC} = 2.3 \text{ V},$	V _I = 1.7 V	Q	-10			-10		μΑ
I _{BHLO}	,¶	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	300			300			μΑ
Івннс) [#]	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	-300			-300			μΑ
{IEX}		$V{CC} = 2.3 \text{ V},$	$V_0 = 5.5 \text{ V}$			125			125	μΑ
IOZ(Pl	J/PD)☆	$V_{CC} \le 1.2 \text{ V}, V_{O} = 0.5 \text{ V}$ $V_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} = 0.5 \text{ V}$	V to V _{CC} , = don't care			±100			±100	μΑ
lozh		V _{CC} = 2.7 V	$V_0 = 2.3 \text{ V},$ $V_1 = 0.7 \text{ V or } 1.7 \text{ V}$			5			5	μΑ
lozL		V _{CC} = 2.7 V	$V_O = 0.5 \text{ V},$ $V_I = 0.7 \text{ V or } 1.7 \text{ V}$			-5			-5	μΑ
		V _{CC} = 2.7 V,	Outputs high	1	0.04	0.1		0.04	0.1	
Icc		$I_{\Omega} = 0$,	Outputs low		2.3	4.5		2.3	4.5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled		0.04	0.1		0.04	0.1	
Ci		V _{CC} = 2.5 V,	V _I = 2.5 V or 0		3.5			3.5		pF
Co		$V_{CC} = 2.5 \text{ V},$	V _O = 2.5 V or 0		6			6		pF

[†] All typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

[¶] An external driver must source at least IBHLO to switch this node from low to high.

[#] An external driver must sink at least I_{BHHO} to switch this node from high to low.

Current into an output in the high state when VO > VCC

[★]High-impedance state during power up or power down

SN54ALVTH16240, SN74ALVTH16240 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

PARAMETER		TEST O	ONDITIONS	SN54	ALVTH1	6240	SN74	ALVTH1	6240	UNIT	
PA	RAMEIER	1531 C	ONDITIONS	MIN	TYP [†]	MAX	MIN	TYP†	MAX	UNII	
VIK		V _{CC} = 3 V,	I _I = -18 mA			-1.2			-1.2	V	
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0.	2		V _{CC} -0	V _{CC} -0.2			
Voн		V 2.V	I _{OH} = -24 mA	2					V		
		VCC = 3 V	I _{OH} = -32 mA				2				
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OL} = 100 μA			0.2			0.2		
			I _{OL} = 16 mA						0.4		
\/0:			I _{OL} = 24 mA			0.5				V	
VOL		V _{CC} = 3 V	$I_{OL} = 32 \text{ mA}$						0.5	V	
			$I_{OL} = 48 \text{ mA}$			0.55					
	_		$I_{OL} = 64 \text{ mA}$								
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1		
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V		Á	10			10		
l _l			V _I = 5.5 V		72/2	10			10	μΑ	
	Data inputs	V _{CC} = 3.6 V	VI = VCC		5	1			1		
			V _I = 0		2	- 5			– 5		
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V	0	2				±100	μΑ	
I _{BHL} ‡		$V_{CC} = 3 V$,	V _I = 0.8 V	75			75			μΑ	
I _{BHH} §		V _{CC} = 3 V,	V _I = 2 V	-75			-75			μΑ	
^I BHLO	1	$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	500			500			μΑ	
Івнно	, #	$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	-500			-500			μΑ	
IEX		$V_{CC} = 3 V$,	V _O = 5.5 V			125			125	μΑ	
IOZ(PL	J/PD)☆	$V_{CC} \le 1.2 \text{ V}, V_{O} = \underline{0.5} \text{ V}$ $V_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} = \underline{0.5} \text{ V}$	V to V _{CC} , = don't care			±100			±100	μΑ	
lozh		V _{CC} = 3.6 V	V _O = 3 V,			5			5	μΑ	
			V _I = 0.8 V or 2 V								
lozL		V _{CC} = 3.6 V	$V_0 = 0.5 \text{ V},$			-5			-5	μΑ	
			V _I = 0.8 V or 2 V	┼	0.07				0.4		
		$V_{CC} = 3.6 \text{ V},$	Outputs high		0.07	0.1		0.07	0.1		
ICC		$I_O = 0$, $V_I = V_{CC}$ or GND	Outputs low	-	3.2	5.5		3.2	5	mA	
			Outputs disabled	₩	0.07	0.1		0.07	0.1		
∆lCC□		V _{CC} = 3 V to 3.6 V, One Other inputs at V _{CC} or	e input at V _{CC} – 0.6 V, GND			0.4			0.4	mA	
C _i		$V_{CC} = 3.3 \text{ V},$	$V_{I} = 3.3 \text{ V or } 0$		3.5			3.5		pF	
Co		V _{CC} = 3.3 V,	V _O = 3.3 V or 0		6			6		pF	

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[□]This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to VCC and then lowering it to VIH min.

 $[\]P$ An external driver must source at least $I_{\mbox{\footnotesize{BHLO}}}$ to switch this node from low to high.

[#] An external driver must sink at least IBHHO to switch this node from high to low.

Current into an output in the high state when VO > VCC

[★]High-impedance state during power up or power down

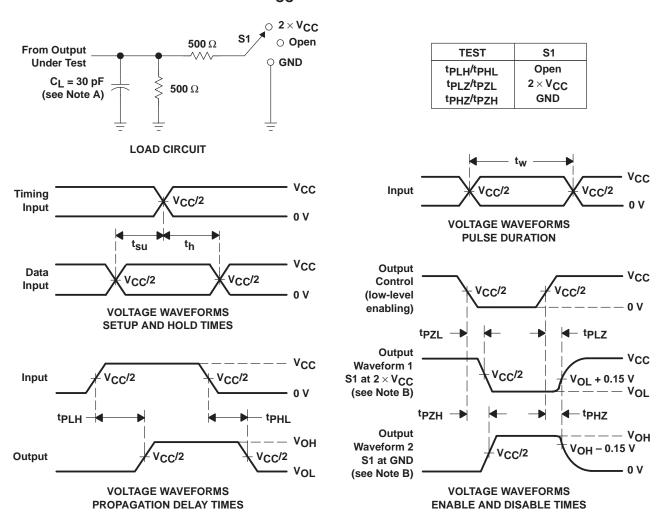
switching characteristics over recommended operating free-air temperature range, C_L = 30 pF, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	SN54ALVTH1624	SN74ALV	SN74ALVTH16240		
PARAMETER	(INPUT)	(OUTPUT)	MIN MA	MIN	MAX	UNIT	
t _{PLH}	۸	V	1 🚜 3.	3 1	3.7	ns	
^t PHL	А	1	1 🚜 3.	6 1	3.5	115	
^t PZH	ŌĒ		1, 5.	4 1	5.3	ns	
^t PZL	OE	1	9 4.	3 1	4.2	115	
^t PHZ	ŌĒ	V	3 1 4.	3 1	4.7	ns	
t _{PLZ}	UE UE	'	1 3.	3 1	3.5	115	

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	SN54ALVTH16	240	SN74ALVTI	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	MIN M	IAX	MIN	MAX	ONIT	
tPLH	۸		1 4	3.4	1	3.3	ns	
t _{PHL}	А	•	1 🖑	3.3	1	3.2	115	
^t PZH	<u>OE</u>	V	1,0	3.8	1	3.7	ns	
tPZL	OE	1	3	3.2	1	3.1	115	
^t PHZ	ŌĒ	V	7.4	5.1	1.5	5	ns	
t _{PLZ}	OE	1	2 1.4	4.2	1.5	4.1	113	

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



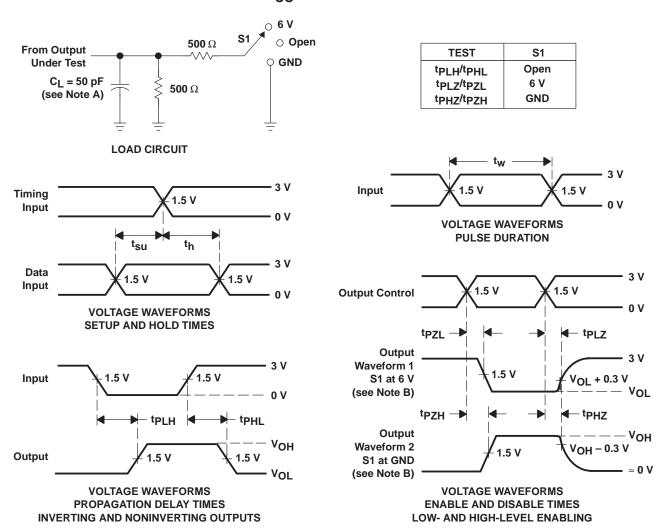
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns. $t_f \leq 2$ ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \ \Omega$, $t_f \leq 2.5 \ ns$.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74ALVTH16240GR	OBSOLETE	TSSOP	DGG	48		TBD	Call TI	Call TI	-40 to 85	ALVTH16240	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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